

1214-32L 32 Watts, 36 Volts Pulsed Radar at 1.2-1.4 GHz

## **GENERAL DESCRIPTION**

The 1214-32L is an internally matched, COMMON BASE transistor capable of providing 32 Watts of pulsed RF output power at 5 milliseconds pulse width, 20% duty factor across the band 1200 to 1400 MHz. This hermetically soldersealed transistor is specifically designed for LBand radar applications. It utilizes gold metallization and diffused emitter ballasting to provide high reliability and supreme ruggedness.

### ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation	
Device Dissipation @ 25°C <sup>1</sup>	125 W
Maximum Voltage and Current	
Collector to Base Voltage (BVces)	50 V
Emitter to Base Voltage (BV <sub>ebo</sub> )	3.5 V
Collector Current (I <sub>c</sub> )	5 A
Maximum Temperatures	
Storage Temperature -65 to	o +200 °C
Operating Junction Temperature	+200 °C

CASE OUTLINE 55AW-1

#### **ELECTRICAL CHARACTERISTICS @ 25°C**

SYMBOL	BOL CHARACTERISTICS TEST CONDITIONS		MIN	ТҮР	MAX	UNITS
$P_{out}^{1}$	F = 1200-1400  MHz		32		41	W
Pg	Power Gain Pin = 5.3 W		7.8		8.9	dB
$\eta_c$	Collector Efficiency	Pulse Width = $5 \text{ mS}$		45		%
R <sub>L</sub>	Return Loss	Duty Factor = 20%				dB
Pd	Pulse Droop				0.5	dB
VSWR <sup>1</sup>	Load Mismatch Tolerance <sup>1</sup>	F=1200 MHz, Pin=5.3 W			3.0:1	

#### FUNCTIONAL CHARACTERISTICS @ 25°C

BV <sub>ebo</sub>	Emitter to Base Breakdown	Ie = 15  mA	3.5		V
BV <sub>ces</sub>	Collector to Emitter Breakdown	Ic = 100 mA	50		V
h <sub>FE</sub>	DC – Current Gain	Vce = 5V, Ic = 1A	20		
θjc <sup>1</sup>	Thermal Resistance			1.4	°C/W

NOTES: 1. Pulse condition of 5 mS, 20%

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# 1214-32L

## Performance Curves

## **Power Output vs Power Input**



## **Input Impedance**



## **Efficiency vs Power Input**



## Load Impedance





Impedance		
Freq	Zs	Z
1200	2.7-j3.6	8.5-j2.8
1300	3-j3.5	8.5-j1.44
1400	3.3-j3.7	9.07-j0.08

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#### 1214-32LR5

### 1214-32L



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